



CY27C512

64K x 8 CMOS EPROM

Features

- **Very Fast Read Access Time: (45 - 200 ns)**
- **5V ± 10% Power Supply**
- **Capable of withstanding >2001V ESD**
- **Latch-up Protection up to 200mA**
- **Two line control functions to prevent bus contention**
- **Standard JEDEC Packages**
 - 32-pin PLCC
 - 28-pin TSOP
 - 28-pin, 600-mil plastic DIP
 - 32-pin, hermetic LCC
 - 28-pin, 600-mil hermetic DIP
- **Available in Commercial, Industrial, and Military Temperature Ranges**

Functional Description

The CY27C512 is a high-performance, 512-Kbit ultraviolet erasable programmable read-only memory (EPROM) organized as 64 Kbytes by 8 bits. It is available in JEDEC-standard, one-time programmable (OTP), 32-pin PLCC and 28-pin PDIP and TSOP packages. The CY27C512

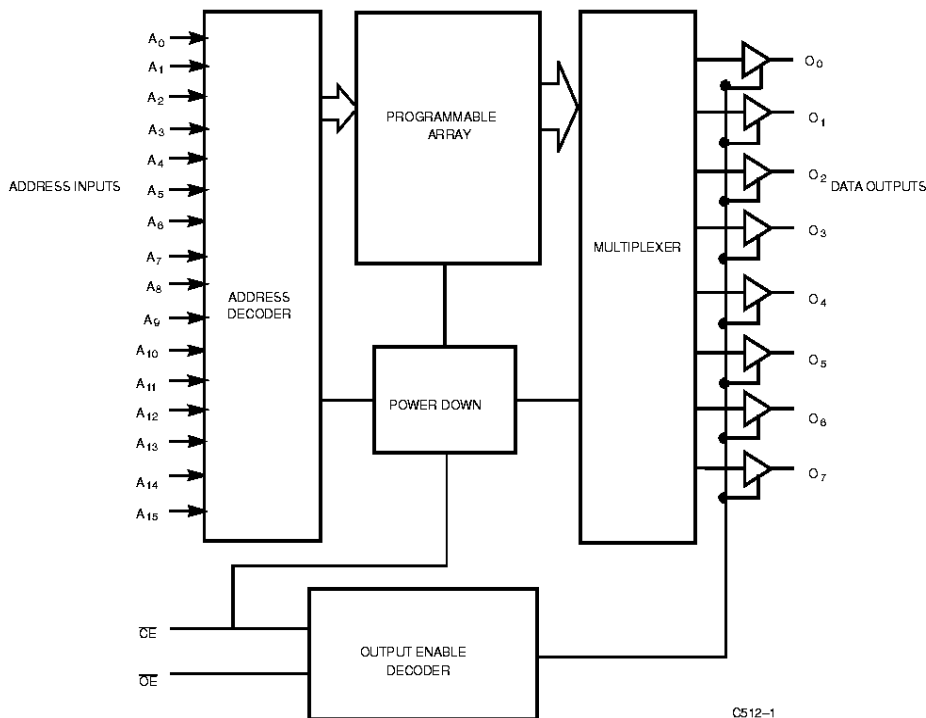
is also available in windowed packages (28-pin hermetic DIP and 32-pin LCC) which allow the device to be erased with UV light for 100% reprogrammability.

The CY27C512 is equipped with a power-down chip enable (\overline{CE}) input and output enable (\overline{OE}) to prevent bus contention. When \overline{CE} is deasserted, the device powers down to a low-power stand-by mode. The \overline{OE} pin three-states the outputs without putting the device into stand-by mode. While \overline{CE} offers lower power, \overline{OE} provides a more rapid transition to and from three-stated outputs.

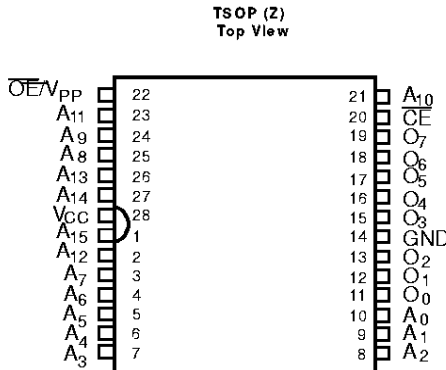
The memory cells utilize proven EPROM floating-gate technology and byte-wide intelligent programming algorithms. The EPROM cell requires only 12.75V for the supervoltage and low programming current allows for gang programming. The device allows for each memory location to be tested 100%, because each location is written to, erased, and repeatedly exercised prior to encapsulation. Each device is also tested for AC performance to guarantee that the product will meet DC and AC specification limits after customer programming.

The CY27C512 is read by asserting both the \overline{CE} and the \overline{OE} inputs. The contents of the memory location selected by the address on inputs A_{15} - A_0 will appear at the outputs O_7 - O_0 .

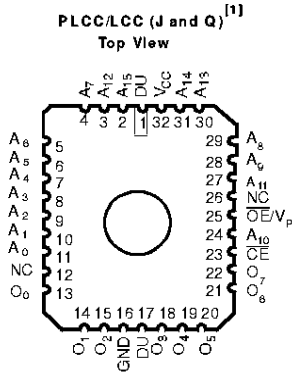
Logic Block Diagram



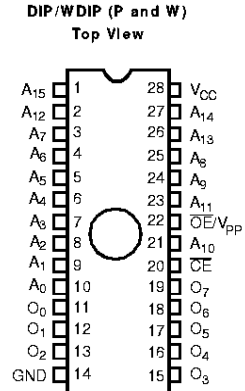
Pin Configurations



C512-2



C512-3



C512-4

Selection Guide

| | | -45 | -55 | -70 | -90 | -120 | -150 | -200 |
|---|------------|-----|-----|-----|-----|------|------|------|
| Maximum Access Time (ns) | | 45 | 55 | 70 | 90 | 120 | 150 | 200 |
| CE Access Time (ns) | | 45 | 55 | 70 | 90 | 120 | 150 | 200 |
| OE Access Time (ns) | | 20 | 20 | 25 | 30 | 40 | 50 | 60 |
| I _{CC} ^[2] (mA) Power Supply Current | Com'l(Max) | 50 | 50 | 50 | 50 | 50 | 50 | 50 |
| | Mil | 60 | 60 | 60 | 60 | 60 | 60 | 60 |
| I _{SB} ^[3] (mA) Stand-by Current | Com'l(Max) | 15 | 15 | 15 | 15 | 15 | 15 | 15 |
| | Mil | 25 | 25 | 25 | 25 | 25 | 25 | 25 |

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

- Storage Temperature -65°C to +150°C
- Ambient Temperature with Power Applied..... -55°C to +125°C
- Supply Voltage to Ground Potential..... -0.5V to +7.0V
- DC Voltage Applied to Outputs in High Z State -0.5V to +5.5V
- DC Input Voltage..... -3.0V to +7.0V
- Transient Input Voltage..... -3.0V for <20 ns
- DC Program Voltage..... 13.0 V

- UV Erasure..... 7258 Wsec/cm²
- Static Discharge Voltage >2001V (per MIL-STD-883, Method 3015)
- Latch-Up Current..... >200 mA

Operating Range

| Range | Ambient Temperature | V _{CC} |
|---------------------------|---------------------|-----------------|
| Commercial | 0°C to +70°C | 5V ± 10% |
| Industrial ^[4] | -40°C to +85°C | 5V ± 10% |
| Military ^[5] | -55°C to +125°C | 5V ± 10% |

Notes:

1. For LCC/PLCC only: Pins 1 and 17 are designated as DU (DON'T USE) and should not be used.
2. V_{CC} = Max., I_{OUT} = 0 mA, f=5 MHz.
3. V_{CC} = Max., CE = V_{IH}.
4. Contact a Cypress representative for industrial temperature range specification.
5. T_A is the "instant on" case temperature.

DC Electrical Characteristics Over the Operating Range^[6, 7]

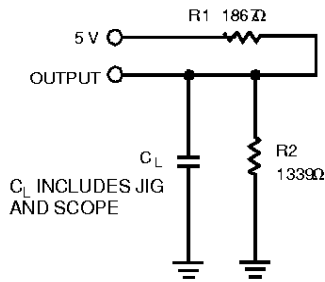
| Parameter | Description | Test Conditions | Min. | Max. | Unit | |
|-----------------|------------------------|---|-------|----------------------|------|----|
| V _{OH} | Output HIGH Voltage | V _{CC} = Min., I _{OH} = -400μA | 2.4 | | V | |
| V _{OL} | Output LOW Voltage | V _{CC} = Min., I _{OL} = 2 mA | | 0.45 | V | |
| V _{IH} | Input HIGH Level | Guaranteed Input Logical HIGH Voltage for All Inputs | 2.0 | V _{CC} +0.5 | V | |
| V _{IL} | Input LOW Level | Guaranteed Input Logical LOW Voltage for All Inputs | | 0.8 | V | |
| I _{LI} | Input Leakage Current | GND ≤ V _{IN} ≤ V _{CC} | -10 | +10 | μA | |
| I _{LO} | Output Leakage Current | GND ≤ V _{OUT} ≤ V _{CC} , Output Disable | -10 | +10 | μA | |
| I _{CC} | Power Supply Current | V _{CC} =Max., I _{OUT} =0 mA, f=5 MHz | Com'l | | 50 | mA |
| | | | Mil | | 60 | mA |
| I _{SB} | Stand-By Current | V _{CC} =Max., $\overline{CE} = V_{IH}$ | Com'l | | 15 | mA |
| | | | Mil | | 25 | mA |

Capacitance^[8]

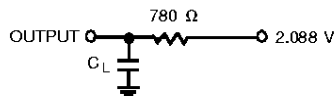
| Parameter | Description | Test Conditions | Max | Unit |
|------------------|--------------------|--|-----|------|
| C _{IN} | Input Capacitance | T _A = 25°C, f = 1 MHz, V _{CC} = 5.0V | 10 | pF |
| C _{OUT} | Output Capacitance | | 10 | pF |

Notes:

6. See the last page of this specification for Group A subgroup testing information.
7. See Introduction to CMOS NVMs in this Data Book for general information on testing.
8. This parameter is sampled only and is not 100% tested.

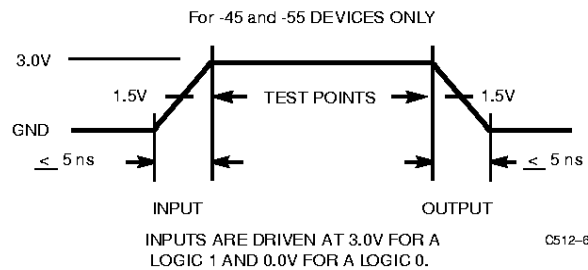
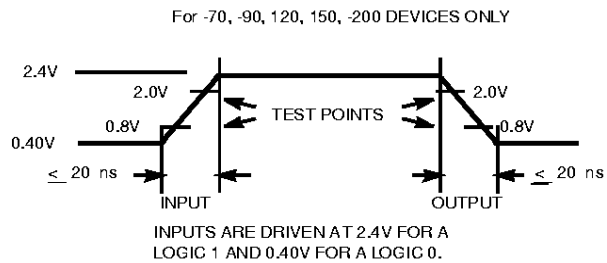
AC Test Loads and Waveforms


THEVENIN EQUIVALENT



- Notes: C_L = 30pF for -45 and -55 devices
 C_L = 100pF for -70, -90, -120, -150, and -200 devices
 C_L = 5pF for t_{DF}

C512-5



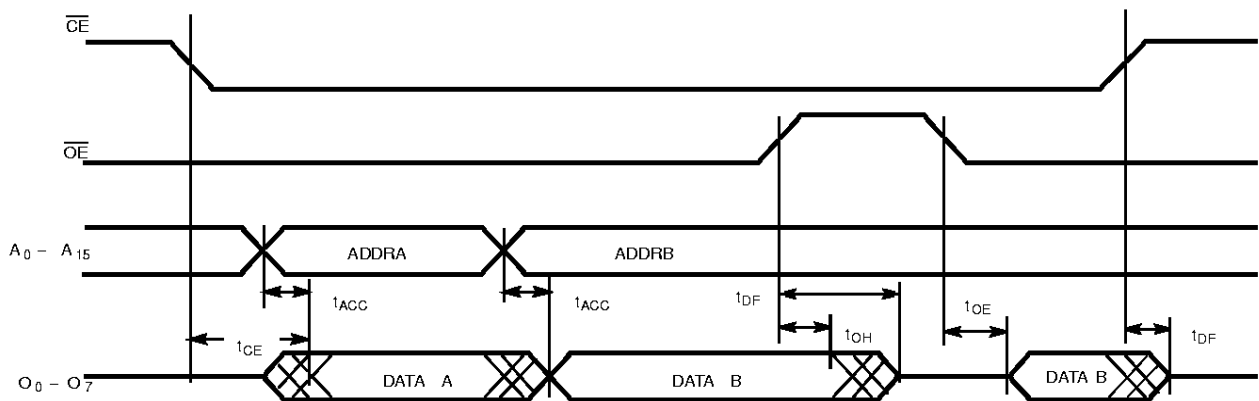
C512-6

Switching Characteristics Over the Operating Range

| Parameter | Description | -45 | | -55 | | -70 | | -90 | | -120 | | -150 | | -200 | | Unit |
|----------------|---|-----|-----|-----|-----|-----|-----|-----|-----|------|-----|------|-----|------|-----|------|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | |
| t_{ACC} | Address to Output Valid | | 45 | | 55 | | 70 | | 90 | | 120 | | 150 | | 200 | ns |
| t_{OE} | \overline{OE} Active to Output Valid | | 20 | | 20 | | 25 | | 30 | | 35 | | 40 | | 60 | ns |
| $t_{DF}^{[9]}$ | \overline{OE} or \overline{CE} Inactive to High Z, whichever occurs first | | 20 | | 20 | | 25 | | 30 | | 30 | | 30 | | 30 | ns |
| t_{CE} | \overline{CE} Active to Output Valid | | 45 | | 55 | | 70 | | 90 | | 120 | | 150 | | 200 | ns |
| t_{OH} | Output Data Hold | 0 | | 0 | | 0 | | 0 | | 0 | | 0 | | 0 | | ns |

Note:

9. This parameter is sampled only and is not 100% tested.

Switching Waveform


CS12-7

Erase Characteristics

Wavelengths of light less than 4000 Angstroms begin to erase the CY27C512 in the windowed package. For this reason, an opaque label should be placed over the window if the EPROM is exposed to sunlight or fluorescent lighting for extended periods of time.

The recommended dose of ultraviolet light for erasure is a wavelength of 2537 Angstroms for a minimum dose (UV intensity multiplied by exposure time) of 15 Wsec/cm². For an ultraviolet lamp with a 12 mW/cm² power rating, the exposure time would be approximately 15 minutes. The CY27C512

needs to be within 1 inch of the lamp during erasure. Permanent damage may result if the EPROM is exposed to high-intensity UV light for an extended period of time. 7258 Wsec/cm² is the recommended maximum dosage.

Programming Modes

Programming support is available from Cypress as well as from a number of third-party software vendors. For detailed programming information, including a listing of software packages, please see the PROM Programming Information located at the end of this section. Programming algorithms can be obtained from any Cypress representative.

Table 1. Programming Electrical Characteristics

| Parameter | Description | Min. | Max. | Unit |
|-----------|--------------------------------|------|----------|------|
| V_{PP} | Programming Power Supply | 12.5 | 13 | V |
| I_{PP} | Programming Supply Current | | 50 | mA |
| V_{IHP} | Programming Input Voltage HIGH | 3.0 | V_{CC} | V |
| V_{ILP} | Programming Input Voltage LOW | -0.5 | 0.4 | V |
| V_{CCP} | Programming V_{CC} | 6.0 | 6.5 | V |

Table 2. Mode Selection

| Mode | Pin Function ^[10] | | | | |
|--------------------------------------|------------------------------|------------------------|----------|--------------|---------|
| | \overline{CE} | \overline{OE}/V_{PP} | A_0 | A_9 | Outputs |
| Read | V_{IL} | V_{IL} | A_0 | A_9 | Dout |
| Output Disable | X | V_{IH} | X | X | High Z |
| Stand-by(TTL) | V_{IH} | X | X | X | High Z |
| Program | V_{ILP} | V_{PP} | A_0 | A_9 | Din |
| Program Verify | V_{ILP} | V_{ILP} | A_0 | A_9 | Dout |
| Program Inhibit | V_{IHP} | V_{PP} | X | X | High Z |
| Signature Read (MFG) ^[12] | V_{IL} | V_{IL} | V_{IL} | $V_{HV}[11]$ | 34H |
| Signature Read (DEV) ^[12] | V_{IL} | V_{IL} | V_{IH} | $V_{HV}[11]$ | 1FH |

Note:

 10. X can be V_{IL} OR V_{IH}

 11. $V_{HV}=12V\pm 0.5V$

 12. $A_1 - A_8$ and $A_{10} - A_{15} = V_{IL}$



Ordering Information ^[10]

| Speed (ns) | Ordering Code | Package Name | Package Type | Operating Range |
|------------|-----------------|--------------|--|-----------------|
| 45 | CY27C512-45JC | J65 | 32-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY27C512-45PC | P15 | 28-Lead (600-Mil) Molded DIP | |
| | CY27C512-45WC | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| | CY27C512-45ZC | Z28 | 28-Lead Thin Small Outline Package | |
| | CY27C512-45QMB | Q55 | 32-Pin Windowed Rectangular Leadless Chip Carrier | Military |
| | CY27C512-45WMB | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| 55 | CY27C512-55JC | J65 | 32-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY27C512-55PC | P15 | 28-Lead (600-Mil) Molded DIP | |
| | CY27C512-55WC | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| | CY27C512-55ZC | Z28 | 28-Lead Thin Small Outline Package | |
| | CY27C512-55QMB | Q55 | 32-Pin Windowed Rectangular Leadless Chip Carrier | Military |
| | CY27C512-55WMB | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| 70 | CY27C512-70JC | J65 | 32-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY27C512-70PC | P15 | 28-Lead (600-Mil) Molded DIP | |
| | CY27C512-70WC | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| | CY27C512-70ZC | Z28 | 28-Lead Thin Small Outline Package | |
| | CY27C512-70QMB | Q55 | 32-Pin Windowed Rectangular Leadless Chip Carrier | Military |
| | CY27C512-70WMB | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| 90 | CY27C512-90JC | J65 | 32-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY27C512-90PC | P15 | 28-Lead (600-Mil) Molded DIP | |
| | CY27C512-90WC | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| | CY27C512-90ZC | Z28 | 28-Lead Thin Small Outline Package | |
| | CY27C512-90QMB | Q55 | 32-Pin Windowed Rectangular Leadless Chip Carrier | Military |
| | CY27C512-90WMB | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| 120 | CY27C512-120JC | J65 | 32-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY27C512-120PC | P15 | 28-Lead (600-Mil) Molded DIP | |
| | CY27C512-120WC | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| | CY27C512-120ZC | Z28 | 28-Lead Thin Small Outline Package | |
| | CY27C512-120QMB | Q55 | 32-Pin Windowed Rectangular Leadless Chip Carrier | Military |
| | CY27C512-120WMB | W16 | 28-Lead (600-Mil) Windowed CerDIP | |



Ordering Information ^[10] (continued)

| Speed (ns) | Ordering Code | Package Name | Package Type | Operating Range |
|------------|-----------------|--------------|---|-----------------|
| 150 | CY27C512-150JC | J65 | 32-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY27C512-150PC | P15 | 28-Lead (600-Mil) Molded DIP | |
| | CY27C512-150WC | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| | CY27C512-150ZC | Z28 | 28-Lead Thin Small Outline Package | |
| | CY27C512-150QMB | Q55 | 32-Pin Windowed Rectangular Leadless Chip Carrier | Military |
| | CY27C512-150WMB | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| 200 | CY27C512-200JC | J65 | 32-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY27C512-200PC | P15 | 28-Lead (600-Mil) Molded DIP | |
| | CY27C512-200WC | W16 | 28-Lead (600-Mil) Windowed CerDIP | |
| | CY27C512-200ZC | Z28 | 28-Lead Thin Small Outline Package | |
| | CY27C512-200QMB | Q55 | 32-Pin Windowed Rectangular Leadless Chip Carrier | Military |
| | CY27C512-200WMB | W16 | 28-Lead (600-Mil) Windowed CerDIP | |

Notes:

13. Contact a Cypress sales representative for industrial temperature offerings.

MILITARY SPECIFICATIONS

Group A Subgroup Testing

DC Characteristics

| Parameter | Subgroups |
|-----------------|-----------|
| V _{OH} | 1, 2, 3 |
| V _{OL} | 1, 2, 3 |
| V _{IH} | 1, 2, 3 |
| V _{IL} | 1, 2, 3 |
| I _{LI} | 1, 2, 3 |
| I _{LO} | 1, 2, 3 |
| I _{CC} | 1, 2, 3 |
| I _{SB} | 1, 2, 3 |

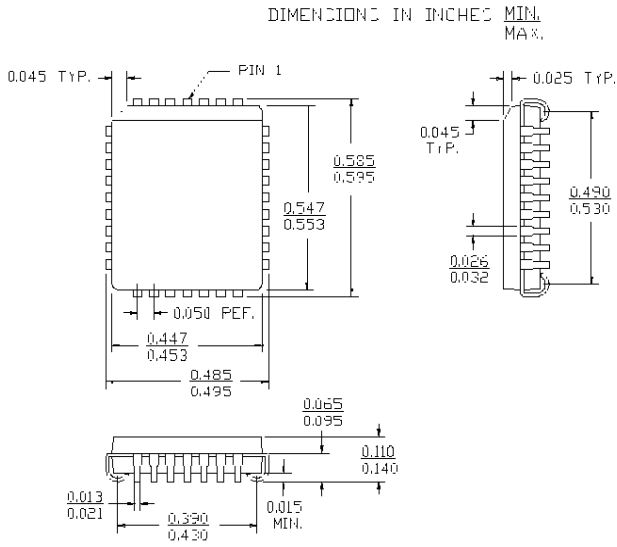
Switching Characteristics

| Parameter | Subgroups |
|------------------|-----------------|
| t _{ACC} | 7, 8, 9, 10, 11 |
| t _{OE} | 7, 8, 9, 10, 11 |
| t _{CE} | 7, 8, 9, 10, 11 |

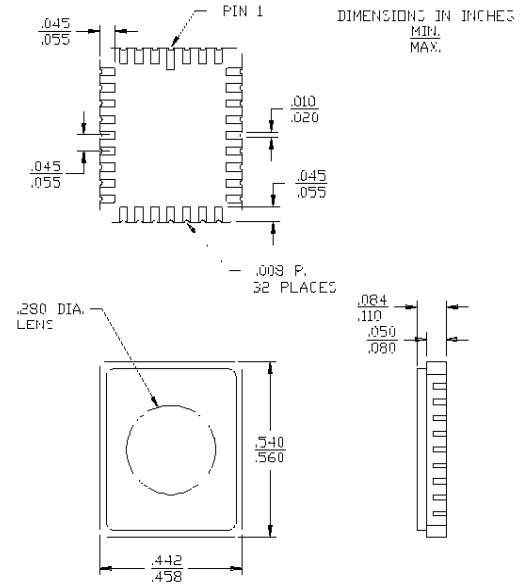
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Package Diagrams

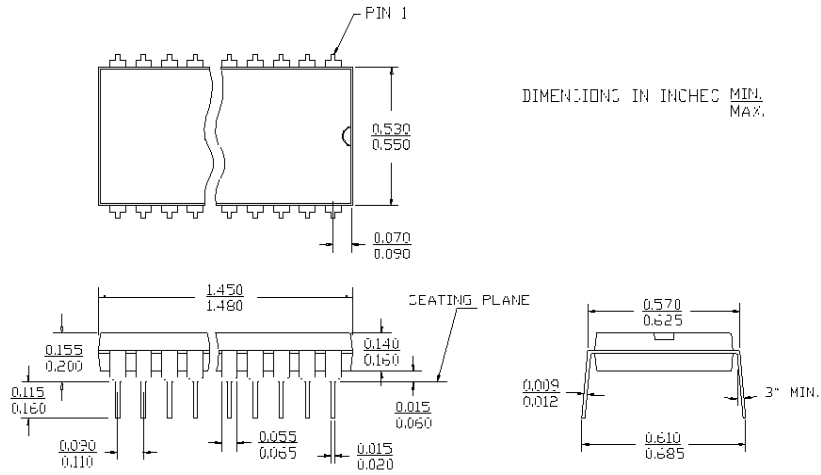
32-Lead Plastic Leaded Chip Carrier J65



32-Pin Windowed Rectangular Leadless Chip Carrier Q55
MIL-STD-1835 C-12

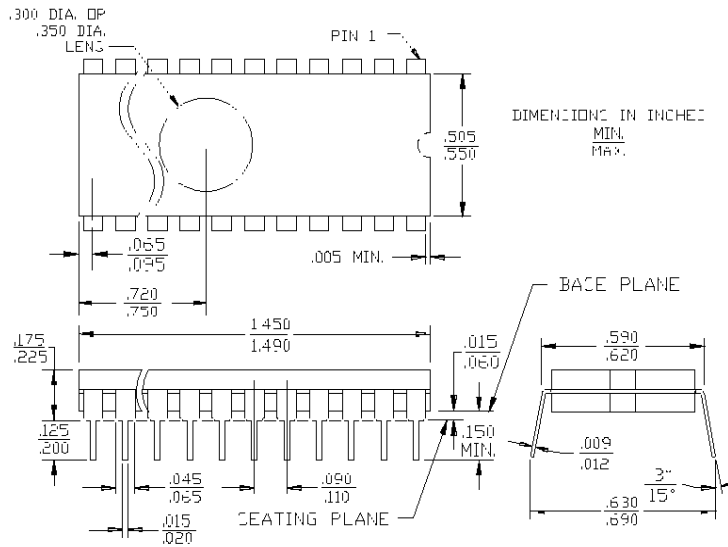


28-Lead (600-Mil) Molded DIP P15



Package Diagrams (continued)
28-Lead (600-Mil) Windowed CerDIP W16

MIL-STD-1835 D- 10Config.A


28-Lead Thin Small Outline Package Z28

 DIMENSION IN MM (INCH)
 MAX.
 MIN.
